

**Average Weight: 14.3584g**

Component	Substance Description	CAS Number or Description	Percentage of Component	Use in Product	Component Weight/ Substance Weight (grams)	Component Percent of Total
<b>Silicon Die</b>					<b>0.446519</b>	<b>3.110%</b>
	Silicon (Si)	7440-21-3	100.00	Basis	0.446519	
<b>Solder Bump</b>					<b>0.018109</b>	<b>0.126%</b>
	Sn	7440-31-5	98.20	basis	0.017783	
	Ag	7440-22-4	1.80	basis	0.000326	
<b>Solder Paste</b>					<b>0.005496</b>	<b>0.038%</b>
	Tin (Sn)	7440-31-5	96.50	Basis	0.005304	
	Silver (Ag)	7440-22-4	3.00	Basis	0.000165	
	Copper (Cu)	7440-50-8	0.50	Basis	0.000027	
<b>Capacitor 1</b>					<b>0.004800</b>	<b>0.033%</b>
	BaTiO3 type	1304-28-5	30.22	Ceramic	0.001451	
	Titanium dioxide	13463-67-7	15.11		0.000725	
	Misc.	trade secret	5.04		0.000242	
	Ni	7440-02-0	33.44	Inner electrode	0.001605	
	Cu	7440-50-8	11.87	Out electrode	0.000570	
	Silicon dioxide	7631-86-9	1.06		0.000051	
	boric oxide	1303-86-2	0.26		0.000012	
	Ni	7440-02-0	0.81	Plating1	0.000039	
	Sn	7440-31-5	2.19	Plating2	0.000105	
<b>Capacitor 2</b>					<b>0.007360</b>	<b>0.051%</b>
	BaTiO3 type	1304-28-5	31.67	Ceramic	0.002331	
	Titanium dioxide	13463-67-7	15.83		0.001165	
	Misc.	-	5.28		0.000389	
	Ni	7440-02-0	26.67	Inner Electrode	0.001963	
	Cu	7440-50-8	15.10	Outer Electrode	0.001111	
	Silicon dioxide	7631-86-9	1.34		0.000099	
	boric oxide	1303-86-2	0.33		0.000024	
	Ni	7440-02-0	1.00	Plating1	0.000074	
	Sn	7440-31-5	2.78	Plating2	0.000205	

Component	Substance Description	CAS Number or Description	Percentage of Component	Use in Product	Component Weight/ Substance Weight (grams)	Component Percent of Total
<b>Capacitor 3</b>					<b>0.037800</b>	<b>0.263%</b>
	BaTiO3 type	1304-28-5	31.67	Ceramic	0.011971	
	Titanium dioxide	13463-67-7	15.83		0.005984	
	Misc.	-	5.28		0.001996	
	Ni	7440-02-0	26.67	Inner Electrode	0.010081	
	Cu	7440-50-8	15.10	Outer Electrode	0.005708	
	Silicon dioxide	7631-86-9	1.34		0.000507	
	boric oxide	1303-86-2	0.33		0.000125	
	Ni	7440-02-0	1.00	Plating1	0.000378	
	Sn	7440-31-5	2.78	Plating2	0.001051	
<b>Underfill</b>					<b>0.053000</b>	<b>0.369%</b>
	Bisphenol F type liquid epoxy resin	9003-36-5	15.00	basis	0.007950	
	1,6-Bis(2,3-epoxypropoxy)naphthalene	27610-48-6	10.00	basis	0.005300	
	Bisphenol A type liquid epoxy resin	25068-38-6	5.00	basis	0.002650	
	Amine type hardener	trade secret	10.00	basis	0.005300	
	Silicon dioxide	60676-86-0	58.00	filler	0.030740	
	Carbon black	1333-86-4	1.00	color agent	0.000530	
	Additives	trade secret	1.00	additives	0.000530	
<b>Lid</b>					<b>8.957100</b>	<b>62.38%</b>
	Cu	7440-50-8	98.35	Main material	8.809308	
	Ni	7440-02-0	1.65	Main material	0.147792	
<b>Lid Adhesive</b>					0.148000	<b>1.031%</b>
	Aluminium Oxide Al2O3	-	80.00	Main material	0.118400	
	Dimethyl siloxane, dimethylvinyl-terminated	68083-19-2	20.00	Main material	0.029600	
<b>Solder Ball</b>					<b>0.965683</b>	<b>6.726%</b>
	Sn	7440-31-5	96.50	basis	0.931884	
	Ag	7440-22-4	3.00	basis	0.028970	
	Cu	7440-50-8	0.50	basis	0.004828	
<b>Substrate</b>					<b>3.714546</b>	<b>25.870%</b>
	Cu	7440-50-8	40.49		1.504096	
	Sn	7440-31-5	0.95		0.035153	
	Ag	7440-22-4	0.03		0.001093	
	Core	trade secret	43.19		1.604315	
	ABF	trade secret	13.16		0.488771	
	Solder Mask	trade secret	2.18		0.081118	

## Revision History

The following table shows the revision history for this document.

Date	Version	Description of Revisions
08/28/2015	1.0	Initial Xilinx release.

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